



Pages 1 to 23

**INTEGRATED CIRCUITS, SILICON MONOLITHIC, HCMOS, 3
TO 8 LINE DECODER/DEMULTIPLEXER WITH FULLY
BUFFERED OUTPUTS**

BASED ON TYPE 54HC238

ESCC Detail Specification No. 9205/016

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DCR No.	CHANGE DESCRIPTION
447, 551	Specification upissued to incorporate editorial and technical changes per DCR.

TABLE OF CONTENTS

1.	<u>GENERAL</u>	5
1.1	Scope	5
1.2	Applicable Documents	5
1.3	Terms, Definitions, Abbreviations, Symbols and Units	5
1.4	The ESCC Component Number and Component Type Variants	5
1.4.1	The ESCC Component Number	5
1.4.2	Component Type Variants	5
1.5	Maximum Ratings	6
1.6	Handling Precautions	6
1.7	Physical Dimensions and Terminal Identification	6
1.7.1	Flat Package (FP) - 16 Pin	7
1.7.2	Dual-in-line Package (DIP) - 16 Pin	8
1.7.3	Chip Carrier Package (CCP) - 20 Terminal	9
1.7.4	Small Outline Ceramic Package (SO) - 16 Pin	11
1.7.5	Notes to Physical Dimensions and Terminal Identification	12
1.8	Functional Diagram	12
1.9	Pin Assignment	13
1.10	Truth Table	13
1.11	Protection Networks	14
2.	<u>REQUIREMENTS</u>	14
2.1	General	14
2.1.1	Deviations from the Generic Specification	14
2.2	Marking	14
2.3	Electrical Measurements at Room, High and Low Temperatures	14
2.3.1	Room Temperature Electrical Measurements	15
2.3.2	High and Low Temperatures Electrical Measurements	17
2.3.3	Notes to Electrical Measurement Tables	19
2.4	Parameter Drift Values	19
2.5	Intermediate and End-Point Electrical Measurements	20
2.6	High Temperature Reverse Bias Burn-in Conditions	21
2.6.1	N-Channel HTRB	21
2.6.2	P-Channel HTRB	22
2.7	Power Burn-in Conditions	22
2.8	Operating Life Conditions	22
APPENDIX 'A'		23

1. GENERAL

1.1 SCOPE

This specification details the ratings, physical and electrical characteristics and test and inspection data for the component type variants and/or the range of components specified below. It supplements the requirements of, and shall be read in conjunction with, the ESCC Generic Specification listed under Applicable Documents.

1.2 APPLICABLE DOCUMENTS

The following documents form part of this specification and shall be read in conjunction with it:

- (a) ESCC Generic Specification No. 9000.
- (b) MIL-STD-883, Test Methods and Procedures for Microelectronics.

1.3 TERMS, DEFINITIONS, ABBREVIATIONS, SYMBOLS AND UNITS

For the purpose of this specification, the terms, definitions, abbreviations, symbols and units specified in ESCC Basic Specification No. 21300 shall apply.

1.4 THE ESCC COMPONENT NUMBER AND COMPONENT TYPE VARIANTS

1.4.1 The ESCC Component Number

The ESCC Component Number shall be constituted as follows:

Example: 920501601

- Detail Specification Reference: 9205016
- Component Type Variant Number: 01 (as required)

1.4.2 Component Type Variants

The component type variants applicable to this specification are as follows:

Variant Number	Based on Type	Case	Terminal Material and /or Finish	Weight max g
01	54HC238	FP	G2	0.7
02	54HC238	FP	G4	0.7
05	54HC238	CCP	2	0.6
10	54HC238	DIP	G2	2.2
11	54HC238	DIP	G4	2.2
12	54HC238	SO	G2	0.7
13	54HC238	SO	G4	0.7

The terminal material and/or finish shall be in accordance with the requirements of ESCC Basic Specification No. 23500.

1.5 MAXIMUM RATINGS

The maximum ratings shall not be exceeded at any time during use or storage.

Maximum ratings shall only be exceeded during testing to the extent specified in this specification and when stipulated in Test Methods and Procedures of the ESCC Generic Specification.

Characteristics	Symbols	Maximum Ratings	Units	Remarks
Supply Voltage	V_{DD}	-0.5 to 7	V	Note 1
Input Voltage	V_{IN}	-0.5 to $V_{DD} + 0.5$	V	Notes 1, 2
Output Voltage	V_{OUT}	-0.5 to $V_{DD} + 0.5$	V	Notes 1, 3
Device Power Dissipation (Continuous)	P_D	300	mW	Note 4
Supply Current	I_{DDop}	50	mA	
Operating Temperature Range	T_{op}	-55 to +125	°C	T_{amb}
Storage Temperature Range	T_{stg}	-65 to +150	°C	
Soldering Temperature For FP, DIP and SO For CCP	T_{sol}	+265 +245	°C	Note 5 Note 6

NOTES:

1. Device is functional for $2V \leq V_{DD} \leq 6V$.
2. Input current limited to $I_{IC} = \pm 20mA$.
3. Output current limited to $I_{OUT} = \pm 25mA$.
4. The maximum device dissipation is determined by $I_{DDop} \max (50mA) \times 6V$.
5. Duration 10 seconds maximum at a distance of not less than 1.5mm from the device body and the same terminal shall not be resoldered until 3 minutes have elapsed.
6. Duration 5 seconds maximum and the same terminal shall not be resoldered until 3 minutes have elapsed.

1.6 HANDLING PRECAUTIONS

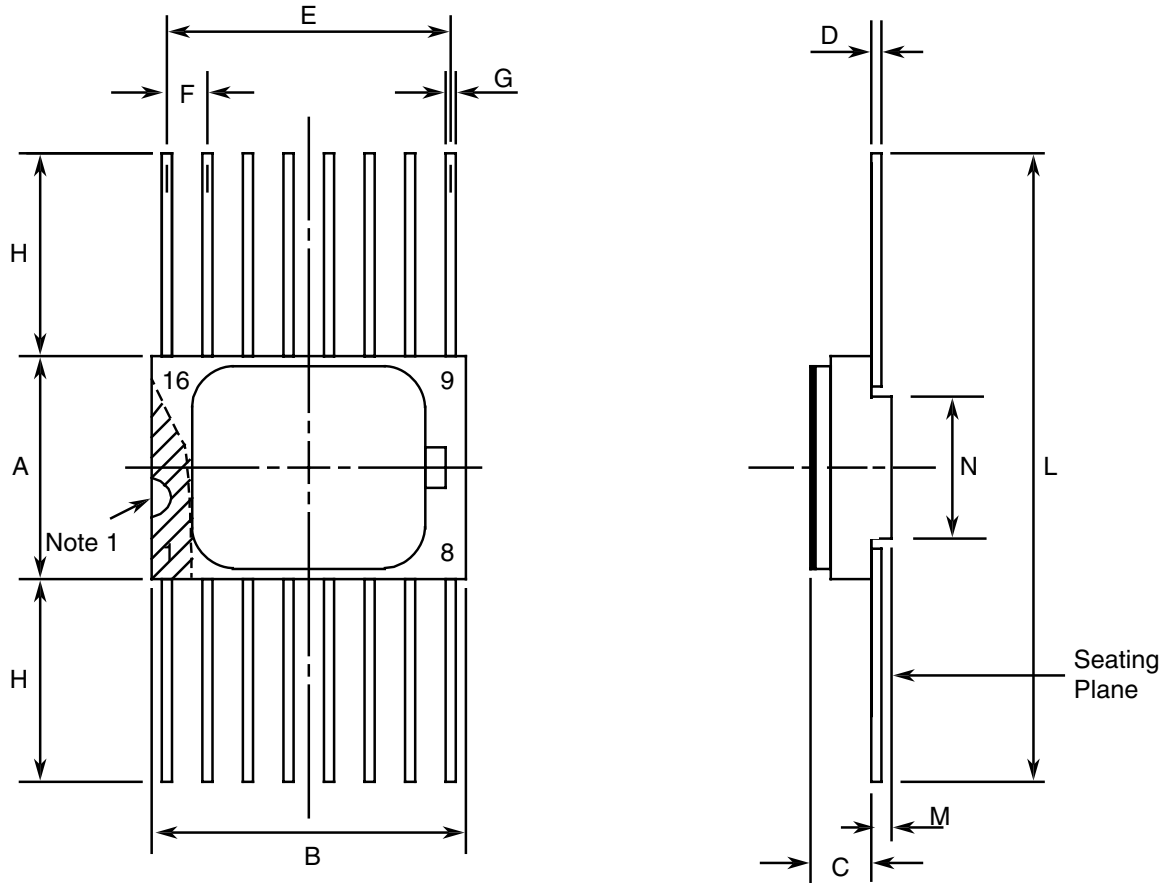
These devices are susceptible to damage by electrostatic discharge. Therefore, suitable precautions shall be employed for protection during all phases of manufacture, testing, packaging, shipment and any handling.

These components are categorised as Class 2 per ESCC Basic Specification No. 23800 with a Minimum Critical Path Failure Voltage of 2500 Volts.

1.7 PHYSICAL DIMENSIONS AND TERMINAL IDENTIFICATION

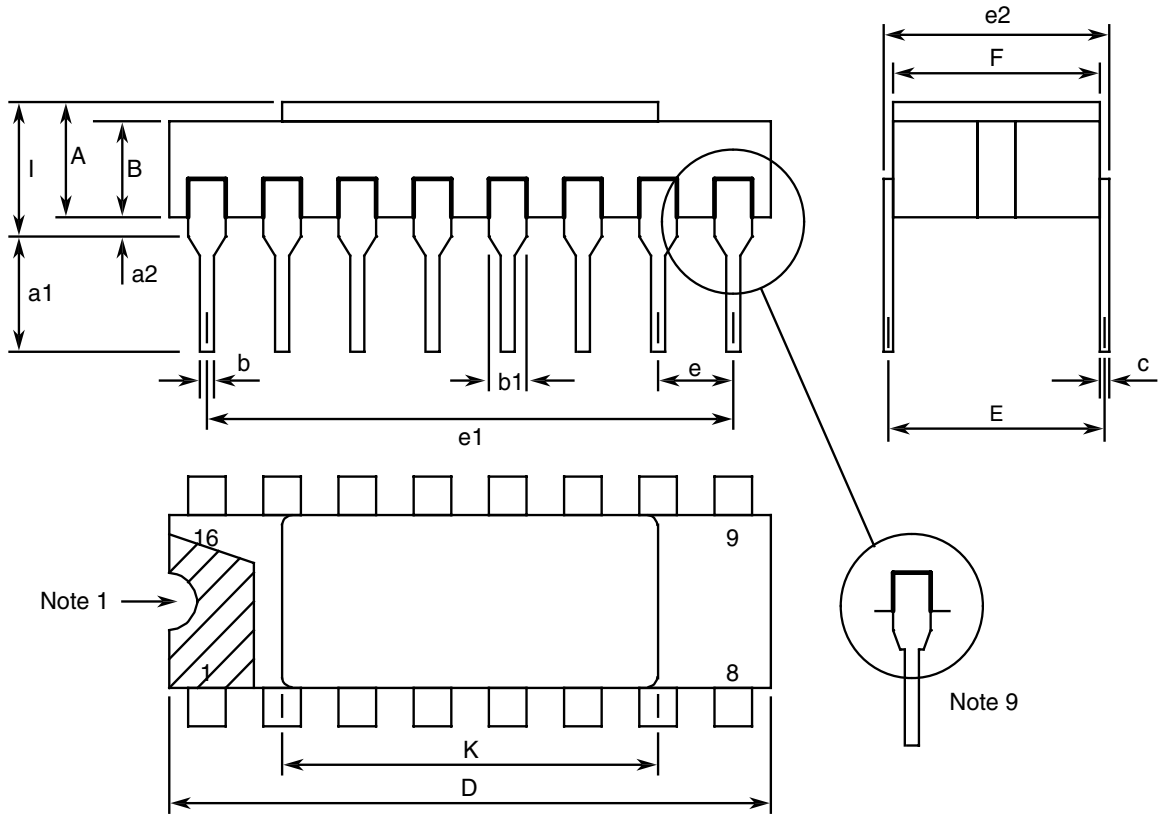
Consolidated Notes are given following the case drawings and dimensions.

1.7.1 Flat Package (FP) - 16 Pin



Symbols	Dimensions mm		Notes
	Min	Max	
A	6.75	7.06	
B	9.76	10.14	
C	1.49	1.95	
D	0.1	0.15	5
E	8.76	9.01	
F	1.27 BSC		3, 6
G	0.38	0.48	5
H	6	-	5
L	18.75	22	
M	0.33	0.43	
N	4.32 TYPICAL		

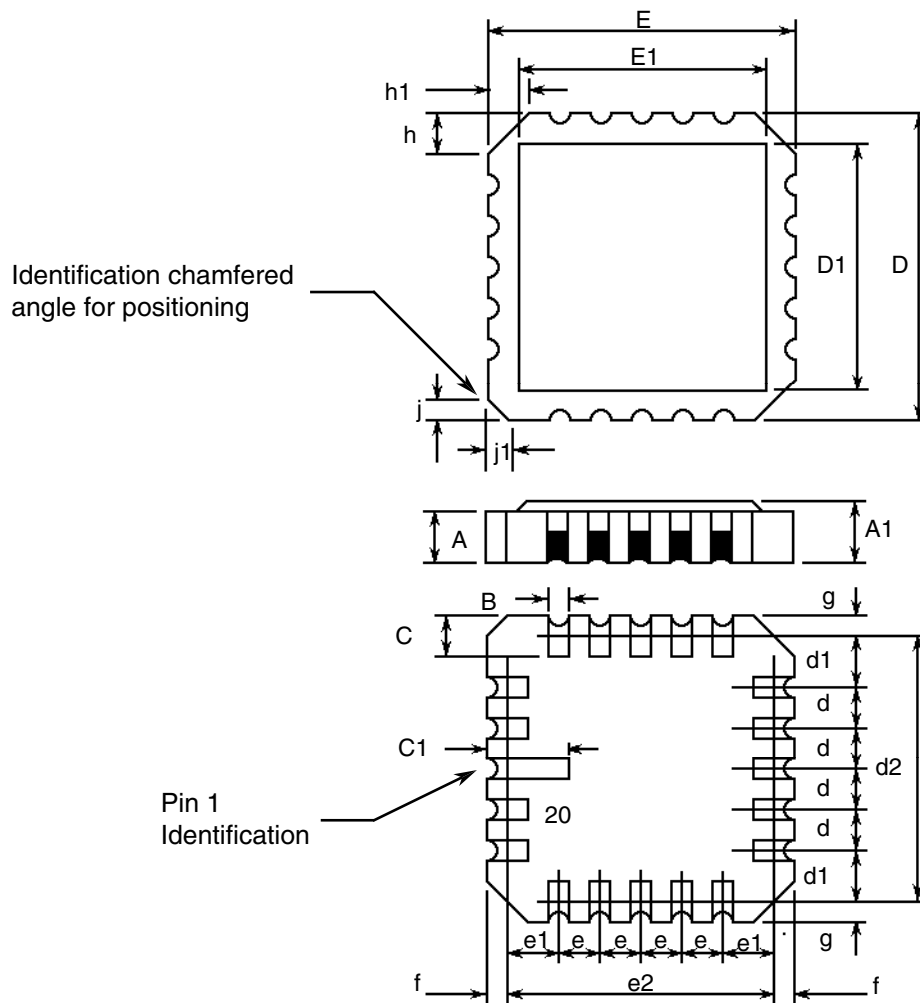
1.7.2 Dual-in-line Package (DIP) - 16 Pin



Symbols	Dimensions mm		Notes
	Min	Max	
A	2.1	2.71	
a1	3	3.7	
a2	0.63	1.14	2
B	1.82	2.39	
b	0.4	0.5	5
b1	1.14	1.5	5
c	0.2	0.3	5
D	20.06	20.58	
E	7.36	7.87	
e	2.54 BSC		4, 6
e1	17.65	17.9	
e2	7.62	8.12	
F	7.29	7.7	
l	-	3.83	

Symbols	Dimensions mm		Notes
	Min	Max	
K	10.9	12.1	

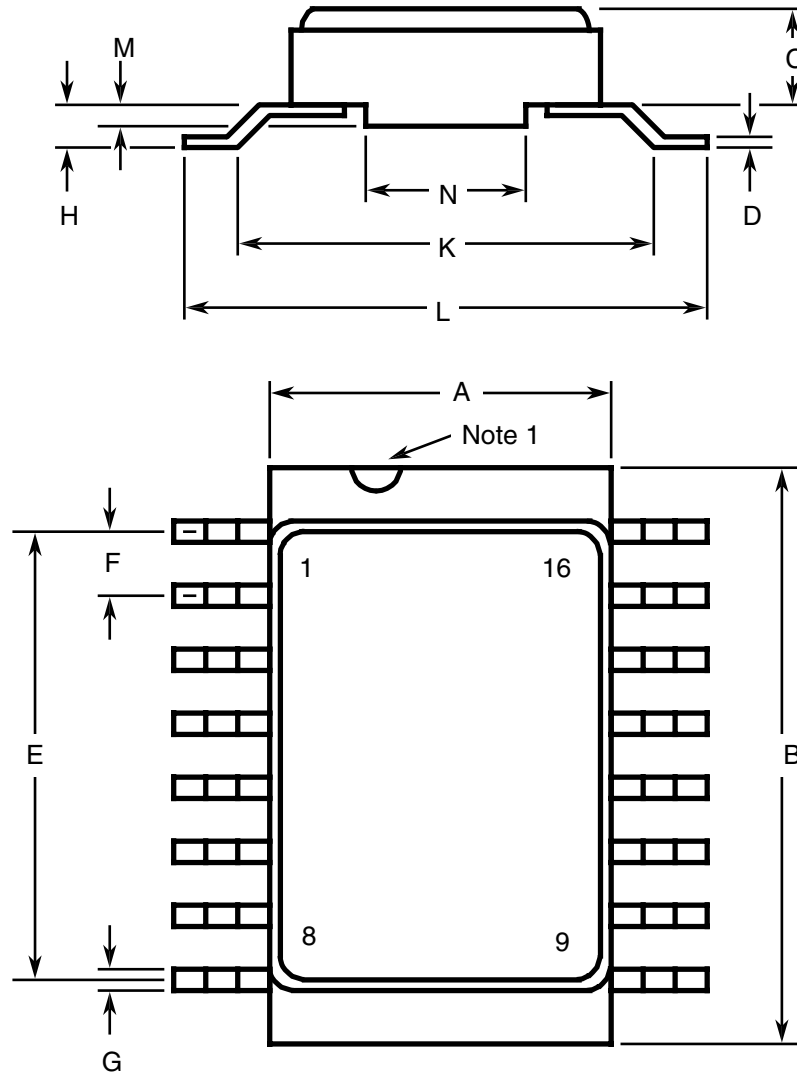
1.7.3 Chip Carrier Package (CCP) - 20 Terminal



Symbols	Dimensions mm		Notes
	Min	Max	
A	1.14	1.95	
A1	1.63	2.36	
B	0.55	0.72	5
C	1.06	1.47	5
C1	1.91	2.41	

Symbols	Dimensions mm		Notes
	Min	Max	
D	8.67	9.09	
D1	7.21	7.52	
d, d1	1.27 BSC		3
d2	7.62 BSC		
E	8.67	9.09	
E1	7.21	7.52	
e, e1	1.27 BSC		3
e2	7.62 BSC		
f, g	-	0.76	
h, h1	1.01 TYPICAL		8
j, j1	0.51 TYPICAL		7

1.7.4 Small Outline Ceramic Package (SO) - 16 Pin



Symbols	Dimensions mm		Notes
	Min	Max	
A	6.75	7.06	
B	9.76	10.14	
C	1.49	1.95	
D	0.1	0.15	5
E	8.76	9.01	
F	1.27 BSC		3, 6
G	0.38	0.48	5
H	0.6	0.9	5

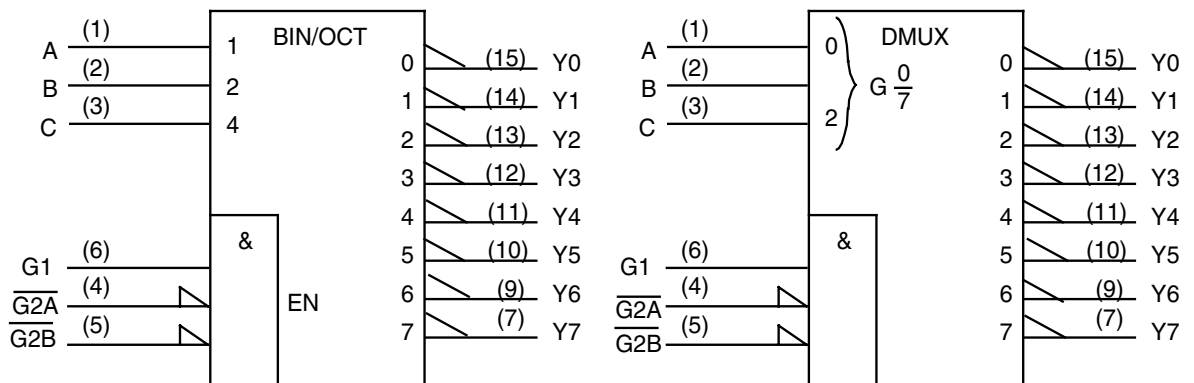
Symbols	Dimensions mm		Notes
	Min	Max	
K	9 TYPICAL		
L	10	10.65	
M	0.33	0.43	
N	4.31 TYPICAL		

1.7.5 Notes to Physical Dimensions and Terminal Identification

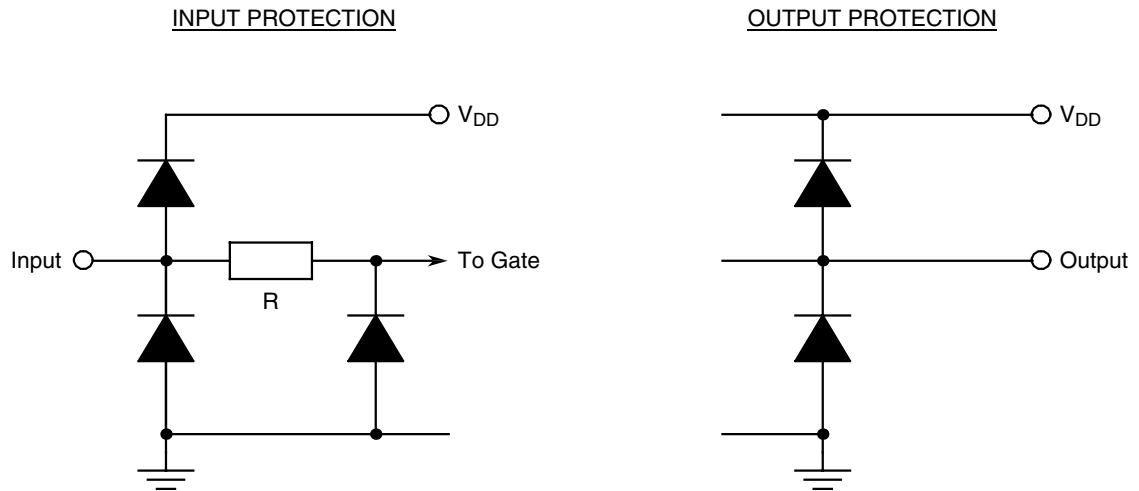
1. Index area; a notch or a dot shall be located adjacent to Pin 1 and shall be within the shaded area shown. For chip carrier packages, the index shall be as shown.
2. The dimension shall be measured from the seating plane to the base plane.
3. The true position pin spacing is 1.27mm between centrelines. Each pin centreline shall be located within $\pm 0.13\text{mm}$ of its true longitudinal position relative to Pin 1 and the highest pin number.
4. The true position pin spacing is 2.54mm between centrelines. Each pin centreline shall be located within $\pm 0.25\text{mm}$ of its true longitudinal position relative to Pin 1 and the highest pin number.
5. All terminals.
6. 14 spaces.
7. Index corner only - 2 dimensions.
8. 3 non-index corners - 6 dimensions.
9. For all pins, either pin shape may be supplied.

1.8 FUNCTIONAL DIAGRAM

Pin numbers relate to FP, DIP and SO packages only.



1.11 PROTECTION NETWORKS



2. REQUIREMENTS

2.1 GENERAL

The complete requirements for procurement of the components specified herein are as stated in this specification and the ESCC Generic Specification. Permitted deviations from the Generic Specification, applicable to this specification only, are listed below.

Permitted deviations from the Generic Specification and this Detail Specification, formally agreed with specific Manufacturers on the basis that the alternative requirements are equivalent to the ESCC requirement and do not affect the component's reliability, are listed in the appendices attached to this specification.

2.1.1 Deviations from the Generic Specification

None.

2.2 MARKING

The marking shall be in accordance with the requirements of ESCC Basic Specification No. 21700 and as follows.

The information to be marked on the component shall be:

- (a) Terminal identification.
- (b) The ESCC qualified components symbol (for ESCC qualified components only).
- (c) The ESCC Component Number.
- (d) Traceability information.

2.3 ELECTRICAL MEASUREMENTS AT ROOM, HIGH AND LOW TEMPERATURES

Electrical measurements shall be performed at room, high and low temperatures. Consolidated Notes

are given after the tables.

2.3.1 Room Temperature Electrical Measurements

The measurements shall be performed at $T_{amb}=+22 \pm 3^{\circ}C$.

Characteristics	Symbols	MIL-STD-883 Test Method	Test Conditions Note 1	Limits		Units
				Min	Max	
Functional Test 1	-	3014	Verify Truth Table without Load $V_{IL}=0.3V, V_{IH}=1.5V$ $V_{DD}=2V, V_{SS}=0V$ $t_r < 1\mu s$, Note 2	-	-	-
Functional Test 2	-	3014	Verify Truth Table without Load $V_{IL}=0.9V, V_{IH}=3.15V$ $V_{DD}=4.5V, V_{SS}=0V$ $t_r=t_f < 500ns$ Note 2	-	-	-
Functional Test 3	-	3014	Verify Truth Table without Load $V_{IL}=1.2V, V_{IH}=4.2V$ $V_{DD}=6V, V_{SS}=0V$ $t_r=t_f < 400ns$ Note 2	-	-	-
Quiescent Current	I_{DD}	3005	$V_{IL}=0V, V_{IH}=6V$ $V_{DD}=6V, V_{SS}=0V$ All Outputs Open Note 3	-	400	nA
Low Level Input Current	I_{IL}	3009	V_{IN} (Under Test)=0V V_{IN} (Remaining Inputs)=6V $V_{DD}=6V, V_{SS}=0V$	-	-50	nA
High Level Input Current	I_{IH}	3010	V_{IN} (Under Test)=6V V_{IN} (Remaining Inputs)=0V $V_{DD}=6V, V_{SS}=0V$	-	50	nA
Low Level Output Voltage 1	V_{OL1}	3007	$V_{IL}=0.3V, V_{IH}=1.5V,$ $I_{OL}=20\mu A$ $V_{DD}=2V, V_{SS}=0V$	-	100	mV
Low Level Output Voltage 2	V_{OL2}	3007	$V_{IL}=0.9V, V_{IH}=3.15V,$ $I_{OL}=20\mu A$ $V_{DD}=4.5V, V_{SS}=0V$	-	100	mV
Low Level Output Voltage 3	V_{OL3}	3007	$V_{IL}=1.2V, V_{IH}=4.2V,$ $I_{OL}=20\mu A$ $V_{DD}=6V, V_{SS}=0V$	-	100	mV
Low Level Output Voltage 4	V_{OL4}	3007	$V_{IL}=0.9V, V_{IH}=3.15V,$ $I_{OL}=4mA$ $V_{DD}=4.5V, V_{SS}=0V$	-	260	mV

Characteristics	Symbols	MIL-STD-883 Test Method	Test Conditions Note 1	Limits		Units
				Min	Max	
Low Level Output Voltage 5	V_{OL5}	3007	$V_{IL}=1.2V, V_{IH}=4.2V,$ $I_{OL}=5.2mA$ $V_{DD}=6V, V_{SS}=0V$	-	260	mV
High Level Output Voltage 1	V_{OH1}	3006	$V_{IL}=0.3V, V_{IH}=1.5V,$ $I_{OH}=-20\mu A$ $V_{DD}=2V, V_{SS}=0V$	1.9	-	V
High Level Output Voltage 2	V_{OH2}	3006	$V_{IL}=0.9V, V_{IH}=3.15V,$ $I_{OH}=-20\mu A$ $V_{DD}=4.5V, V_{SS}=0V$	4.4	-	V
High Level Output Voltage 3	V_{OH3}	3006	$V_{IL}=1.2V, V_{IH}=4.2V,$ $I_{OH}=-20\mu A$ $V_{DD}=6V, V_{SS}=0V$	5.9	-	V
High Level Output Voltage 4	V_{OH4}	3006	$V_{IL}=0.9V, V_{IH}=3.15V,$ $I_{OH}=-4mA$ $V_{DD}=4.5V, V_{SS}=0V$	3.98	-	V
High Level Output Voltage 5	V_{OH5}	3006	$V_{IL}=1.2V, V_{IH}=4.2V,$ $I_{OH}=-5.2mA$ $V_{DD}=6V, V_{SS}=0V$	5.48	-	V
Threshold Voltage N-Channel	V_{THN}	-	A Input at Ground All Other Inputs: $V_{IN}=5V$ $V_{DD}=5V, I_{SS}=-10\mu A$	-0.45	-1.45	V
Threshold Voltage P-Channel	V_{THP}	-	A Input at Ground All Other Inputs: $V_{IN}=-5V$ $V_{SS}=-5V, I_{DD}=10\mu A$	0.45	1.35	V
Input Clamp Voltage 1, to V_{SS}	V_{IC1}	-	I_{IN} (Under Test)= -100 μA $V_{DD}=\text{Open}, V_{SS}=0V$ All Other Pins Open	-400	-900	mV
Input Clamp Voltage 2, to V_{DD}	V_{IC2}	-	I_{IN} (Under Test)= 100 μA $V_{DD}=0V, V_{SS}=\text{Open}$ All Other Pins Open	400	900	mV
Input Capacitance	C_{IN}	3012	V_{IN} (Not Under Test)=0V $V_{DD}=V_{SS}=0V$ $f = 100 \text{ kHz to } 1 \text{ MHz}$ Note 4	-	10	pF
Propagation Delay Low to High 1, A to Y7	t_{PLH1}	3003	V_{IN} (Under Test)=Pulse Generator V_{IN} (Remaining Inputs)=Truth Table $V_{IL}=0V, V_{IH}=4.5V$ $V_{DD}=4.5V, V_{SS}=0V$ Note 5	-	36	ns

Characteristics	Symbols	MIL-STD-883 Test Method	Test Conditions Note 1	Limits		Units
				Min	Max	
Propagation Delay High to Low 1, A to Y7	t_{PHL1}	3003	$V_{IN}(\text{Under Test})=\text{Pulse Generator}$ $V_{IN}(\text{Remaining Inputs})=\text{Truth Table}$ $V_{IL}=0V, V_{IH}=4.5V$ $V_{DD}=4.5V, V_{SS}=0V$ Note 5	-	36	ns
Propagation Delay Low to High 2, G2A to Y7	t_{PLH2}	3003	$V_{IN}(\text{Under Test})=\text{Pulse Generator}$ $V_{IN}(\text{Remaining Inputs})=\text{Truth Table}$ $V_{IL}=0V, V_{IH}=4.5V$ $V_{DD}=4.5V, V_{SS}=0V$ Note 5	-	34	ns
Propagation Delay High to Low 2, G2A to Y7	t_{PHL2}	3003	$V_{IN}(\text{Under Test})=\text{Pulse Generator}$ $V_{IN}(\text{Remaining Inputs})=\text{Truth Table}$ $V_{IL}=0V, V_{IH}=4.5V$ $V_{DD}=4.5V, V_{SS}=0V$ Note 5	-	34	ns
Transition Time Low to High Y0	t_{TLH}	3004	$V_{IN}(\text{Under Test})=\text{Pulse Generator}$ $V_{IN}(\text{Remaining Inputs})=\text{Truth Table}$ $V_{IL}=0V, V_{IH}=4.5V$ $V_{DD}=4.5V, V_{SS}=0V$ Note 5	-	15	ns
Transition Time High to Low Y0	t_{THL}	3004	$V_{IN}(\text{Under Test})=\text{Pulse Generator}$ $V_{IN}(\text{Remaining Inputs})=\text{Truth Table}$ $V_{IL}=0V, V_{IH}=4.5V$ $V_{DD}=4.5V, V_{SS}=0V$ Note 5	-	15	ns

2.3.2 High and Low Temperatures Electrical Measurements

The measurements shall be performed at $T_{amb}=+125 (+0 -5) ^\circ C$ and $T_{amb}=- 55(+5-0)^\circ C$.

Characteristics	Symbols	MIL-STD-883 Test Method	Test Conditions Note 1	Limits		Units
				Min	Max	
Functional Test 1	-	3014	Verify Truth Table without Load $V_{IL}=0.3V, V_{IH}=1.5V$ $V_{DD}=2V, V_{SS}=0V$ $t_r < 1\mu s$, Note 2	-	-	-

Characteristics	Symbols	MIL-STD-883 Test Method	Test Conditions Note 1	Limits		Units
				Min	Max	
Functional Test 2	-	3014	Verify Truth Table without Load $V_{IL}=0.9V, V_{IH}=3.15V$ $V_{DD}=4.5V, V_{SS}=0V$ $t_r=t_f<500ns$ Note 2	-	-	-
Functional Test 3	-	3014	Verify Truth Table without Load $V_{IL}=1.2V, V_{IH}=4.2V$ $V_{DD}=6V, V_{SS}=0V$ $t_r=t_f<400ns$ Note 2	-	-	-
Quiescent Current	I_{DD}	3005	$V_{IL}=0V, V_{IH}=6V$ $V_{DD}=6V, V_{SS}=0V$ All Outputs Open Note 3	-	8	μA
Low Level Input Current	I_{IL}	3009	V_{IN} (Under Test)=0V V_{IN} (Remaining Inputs)=6V $V_{DD}=6V, V_{SS}=0V$	-	-1	μA
High Level Input Current	I_{IH}	3010	V_{IN} (Under Test)=6V V_{IN} (Remaining Inputs)=0V $V_{DD}=6V, V_{SS}=0V$	-	1	μA
Low Level Output Voltage 1	V_{OL1}	3007	$V_{IL}=0.3V, V_{IH}=1.5V,$ $I_{OL}=20\mu A$ $V_{DD}=2V, V_{SS}=0V$	-	100	mV
Low Level Output Voltage 2	V_{OL2}	3007	$V_{IL}=0.9V, V_{IH}=3.15V,$ $I_{OL}=20\mu A$ $V_{DD}=4.5V, V_{SS}=0V$	-	100	mV
Low Level Output Voltage 3	V_{OL3}	3007	$V_{IL}=1.2V, V_{IH}=4.2V,$ $I_{OL}=20\mu A$ $V_{DD}=6V, V_{SS}=0V$	-	100	mV
Low Level Output Voltage 4	V_{OL4}	3007	$V_{IL}=0.9V, V_{IH}=3.15V,$ $I_{OL}=4mA$ $V_{DD}=4.5V, V_{SS}=0V$	-	400	mV
Low Level Output Voltage 5	V_{OL5}	3007	$V_{IL}=1.2V, V_{IH}=4.2V,$ $I_{OL}=5.2mA$ $V_{DD}=6V, V_{SS}=0V$	-	400	mV
High Level Output Voltage 1	V_{OH1}	3006	$V_{IL}=0.3V, V_{IH}=1.5V,$ $I_{OH}=-20\mu A$ $V_{DD}=2V, V_{SS}=0V$	1.9	-	V
High Level Output Voltage 2	V_{OH2}	3006	$V_{IL}=0.9V, V_{IH}=3.15V,$ $I_{OH}=-20\mu A$ $V_{DD}=4.5V, V_{SS}=0V$	4.4	-	V

Characteristics	Symbols	MIL-STD-883 Test Method	Test Conditions Note 1	Limits		Units
				Min	Max	
High Level Output Voltage 3	V_{OH3}	3006	$V_{IL}=1.2V, V_{IH}=4.2V,$ $I_{OH}=-20\mu A$ $V_{DD}=6V, V_{SS}=0V$	5.9	-	V
High Level Output Voltage 4	V_{OH4}	3006	$V_{IL}=0.9V, V_{IH}=3.15V,$ $I_{OH}=-4mA$ $V_{DD}=4.5V, V_{SS}=0V$	3.7	-	V
High Level Output Voltage 5	V_{OH5}	3006	$V_{IL}=1.2V, V_{IH}=4.2V,$ $I_{OH}=-5.2mA$ $V_{DD}=6V, V_{SS}=0V$	5.2	-	V
Input Clamp Voltage 1, to V_{SS}	V_{IC1}	-	I_{IN} (Under Test)= -100 μA V_{DD} =Open, $V_{SS}=0V$ All Other Pins Open	-0.1	-1.2	V
Input Clamp Voltage 2, to V_{DD}	V_{IC2}	-	I_{IN} (Under Test)= 100 μA $V_{DD}=0V, V_{SS}$ =Open All Other Pins Open	0.1	1.2	V

2.3.3 Notes to Electrical Measurement Tables

- Unless otherwise specified all inputs and outputs shall be tested for each characteristic, inputs not under test shall be $V_{IN} = V_{SS}$ or V_{DD} and outputs not under test shall be open.
- Functional tests shall be performed with $f = 10$ kHz (min). The maximum time to output comparator strobe=30 μs .
- Quiescent Current shall be tested using the following input conditions:
 - All inputs = V_{IH}
 - G1 = V_{IH} ; all other inputs= V_{IL}
- Guaranteed but not tested.
- Measurements shall be performed as a go-no-go test on a 100% basis. Read and record measurements shall be performed on a sample of 5 components.
The pulse generator shall have the following characteristics:
 $V_{GEN} = 0$ to V_{DD} ; $f_{GEN} = 1$ MHz minimum; t_r and $t_f \leq 6$ ns (10% to 90%); duty cycle = 50%; $Z_{out} = 50\Omega$.
Output load capacitance $C_L = 50pF \pm 5\%$ including scope probe, wiring and stray capacitance without component in the test fixture and output load resistance $R_L = 1k\Omega \pm 5\%$.
Propagation delay shall be measured referenced to the 50% input and output voltages.
Transition time shall be measured referenced to the 10% and 90% output voltage.

2.4 PARAMETER DRIFT VALUES

Unless otherwise specified, the measurements shall be performed at $T_{amb} = +22 \pm 3^\circ C$.

The test methods and test conditions shall be as per the corresponding test defined in Room Temperature Electrical Measurements.

The drift values (Δ) shall not be exceeded for each characteristic specified. The corresponding absolute limit values for each characteristic shall not be exceeded.

Characteristics	Symbols	Limits			Units
		Drift Value Δ	Absolute		
			Min	Max	
Quiescent Current	I_{DD}	± 120	-	400	nA
Low Level Input Current	I_{IL}	± 20	-	-50	nA
High Level Input Current	I_{IH}	± 20	-	50	nA
Low Level Output Voltage 4	V_{OL4}	± 26	-	260	mV
High Level Output Voltage 4	V_{OH4}	± 0.2	3.98	-	V
Threshold Voltage N-Channel	V_{THN}	± 0.3	-0.45	-1.45	V
Threshold Voltage P-Channel	V_{THP}	± 0.3	0.45	1.35	V

NOTES:

1. Unless otherwise specified all inputs and outputs shall be tested for each characteristic.

2.5

INTERMEDIATE AND END-POINT ELECTRICAL MEASUREMENTS

Unless otherwise specified, the measurements shall be performed at $T_{amb} = +22 \pm 3^{\circ}C$.

The test methods and test conditions shall be as per the corresponding test defined in Room Temperature Electrical Measurements.

The drift values (Δ) shall not be exceeded for each characteristic where specified. The corresponding absolute limit values for each characteristic shall not be exceeded.

Characteristics	Symbols	Limits			Units
		Drift Value Δ	Absolute		
			Min	Max	
Functional Test 1	-	-	-	-	-
Functional Test 2	-	-	-	-	-
Functional Test 3	-	-	-	-	-
Quiescent Current	I_{DD}	± 120	-	400	nA
Low Level Input Current	I_{IL}	± 20	-	-50	nA
High Level Input Current	I_{IH}	± 20	-	50	nA
Low Level Output Voltage 4	V_{OL4}	± 26	-	260	mV
Low Level Output Voltage 5	V_{OL5}	± 26	-	260	mV
High Level Output Voltage 4	V_{OH4}	± 0.2	3.98	-	V
High Level Output Voltage 5	V_{OH5}	± 0.2	5.48	-	V
Threshold Voltage N-Channel	V_{THN}	± 0.3	-0.45	-1.45	V
Threshold Voltage P-Channel	V_{THP}	± 0.3	0.45	1.35	V

NOTES:

1. Unless otherwise specified all inputs and outputs shall be tested for each characteristic.
2. The drift values (Δ) are applicable to the Operating Life test only.

2.6 HIGH TEMPERATURE REVERSE BIAS BURN-IN CONDITIONS

2.6.1 N-Channel HTRB

Characteristics	Symbols	Test Conditions	Units
Ambient Temperature	T_{amb}	+125 (+0 -5)	$^{\circ}C$
Outputs Y0, Y1, Y2, Y3, Y4, Y5, Y6, Y7	V_{OUT}	Open or V_{SS}	V
Inputs A, B, C, $\overline{G2A}$, $\overline{G2B}$, G1	V_{IN}	V_{SS}	V
Positive Supply Voltage	V_{DD}	6 (+0 -0.5)	V
Negative Supply Voltage	V_{SS}	0	V
Duration	t	72	Hours

NOTES:

1. Input Protection Resistor = 680 Ω min to 47k Ω max.
2. Output Load = 1k Ω min to 10k Ω max.

2.6.2 P-Channel HTRB

Characteristics	Symbols	Test Conditions	Units
Ambient Temperature	T_{amb}	+125 (+0 -5)	°C
Outputs Y0, Y1, Y2, Y3, Y4, Y5, Y6, Y7	V_{OUT}	Open or V_{DD}	V
Inputs A, B, C, $\overline{G2A}$, $\overline{G2B}$, G1	V_{IN}	V_{DD}	V
Positive Supply Voltage	V_{DD}	6 (+0 -0.5)	V
Negative Supply Voltage	V_{SS}	0	V
Duration	t	72	Hours

NOTES:

1. Input Protection Resistor = 680Ω min to 47kΩ max.
2. Output Load = 1kΩ min to 10kΩ max.

2.7 POWER BURN-IN CONDITIONS

Characteristics	Symbols	Test Conditions	Units
Ambient Temperature	T_{amb}	+125 (+0 -5)	°C
Outputs Y0, Y1, Y2, Y3, Y4, Y5, Y6, Y7	V_{OUT}	V_{DD}	V
Input G1	V_{IN}	V_{DD}	V
Inputs $\overline{G2A}$, $\overline{G2B}$	V_{IN}	V_{SS}	V
Input A	V_{IN}	V_{GEN1}	V
Input B	V_{IN}	V_{GEN2}	V
Input C	V_{IN}	V_{GEN3}	V
Pulse Voltage	V_{GEN}	0V to V_{DD}	V
Pulse Frequency Square Wave	f_{GEN1} f_{GEN2} f_{GEN3}	100k ± 10% 50k ± 10% 25k ± 10% 50 ± 15% Duty Cycle $t_r=t_f \leq 400ns$	Hz
Positive Supply Voltage	V_{DD}	6 (+0 -0.5)	V
Negative Supply Voltage	V_{SS}	0	V

NOTES:

1. Input Protection Resistor = 680Ω min to 47kΩ max.
2. Output Load = 1kΩ min to 10kΩ max.

2.8 OPERATING LIFE CONDITIONS

The conditions shall be as specified for Power Burn-in.

APPENDIX 'A'

AGREED DEVIATIONS FOR STMICROELECTRONICS (F)

ITEMS AFFECTED	DESCRIPTION OF DEVIATIONS
<p>Deviations from Screening Tests - Chart F3</p>	<p>External Visual Inspection: The criteria applicable to chip-outs are those described in MIL-STD-883, Test Method 2009, Paras 3.3.6(b) and 3.3.7(a).</p> <p>High Temperature Reverse Bias Burn-in: The temperature limits of MIL-STD-883, Para. 4.5.8(c) may be used.</p> <p>Power Burn-in test is performed using STMicroelectronics Specification Ref: 0019255.</p> <p>Solderability is not applicable unless specifically stipulated in the Purchase Order.</p>
<p>Deviations from Qualification and Periodic Tests - Chart F4</p>	<p>External Visual Inspection: The criteria applicable to chip-outs are those described in MIL-STD-883, Test Method 2009, Paras 3.3.6(b) and 3.3.7(a).</p> <p>Operating Life: The temperature limits of MIL-STD-883, Para. 4.5.8(c) may be used.</p>
<p>Deviations from High and Low Temperatures Electrical Measurements</p>	<p>High and Low Temperatures Electrical Measurements may be considered guaranteed but not tested if successful pilot lot testing has been performed on the wafer lot which includes High and Low Temperatures Electrical Measurements per the Detail Specification.</p> <p>A summary of the pilot lot testing shall be provided if required by the Purchase Order.</p>
<p>Deviations from Room Temperature Electrical Measurements</p>	<p>All AC characteristics (Capacitance and Timings) may be considered guaranteed but not tested if successful pilot lot testing has been performed on the wafer lot which includes AC characteristic measurements per the Detail Specification.</p> <p>A summary of the pilot lot testing shall be provided if required by the Purchase Order.</p>